

Appl. No. 10/646,206

Preliminary Amdt. dated September 24, 2004

**Amendments to the Abstract:**

Amend the Abstract as follows:

**Abstract of the Disclosure:**

A semiconductor product has an anti-reflective coating layer covering a semiconductor substrate. The ARG anti-reflective component layer is formed of a matrix substance and of nanocrystalline particles of another material than the matrix substance. The nanocrystalline particles absorb light via the quantum size effect, that is, the novel kind of ARG anti-reflective component layer is an absorbing ARG anti-reflective component layer.